

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	I_D
20V	18mΩ@4.5V	5A
	24mΩ@2.5V	

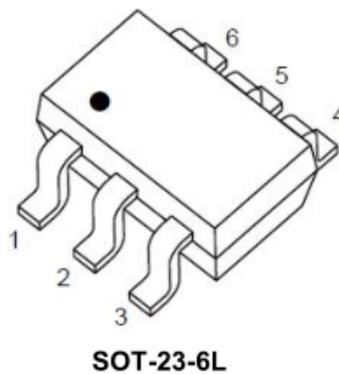
Feature

- Low gate charge
- Low RDS(on)

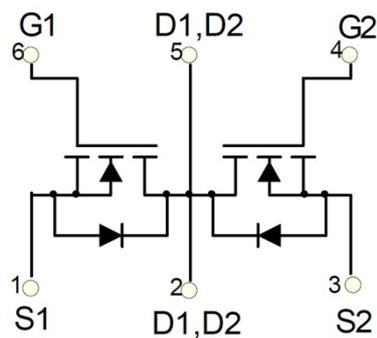
Applications

- Battery protection
- Switching application.

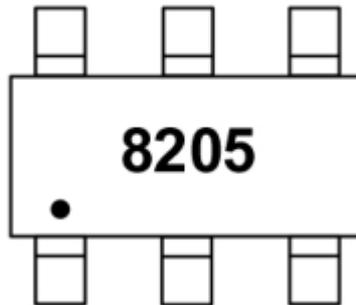
Package



Circuit diagram



Marking



Absolute maximum ratings

($T_a=25^{\circ}\text{C}$ unless otherwise noted)

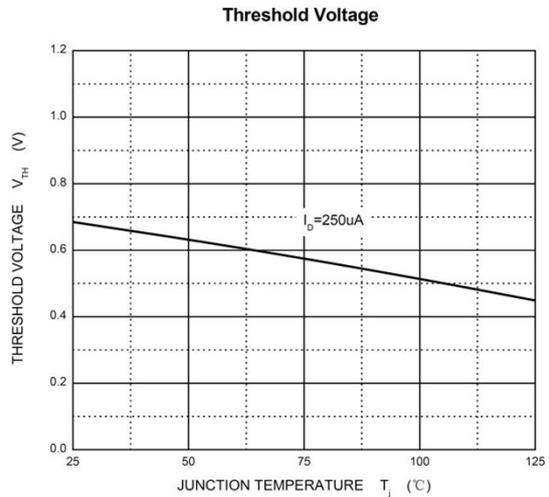
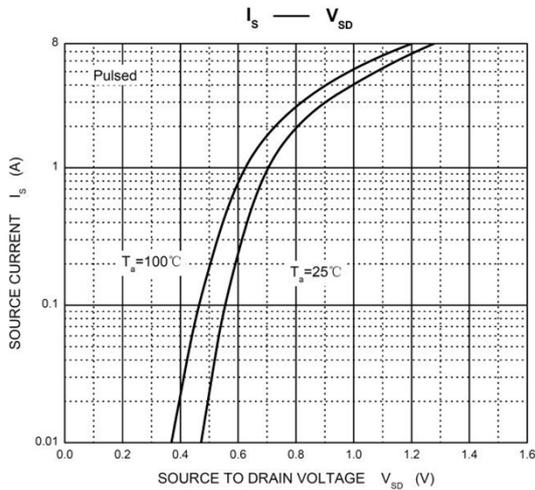
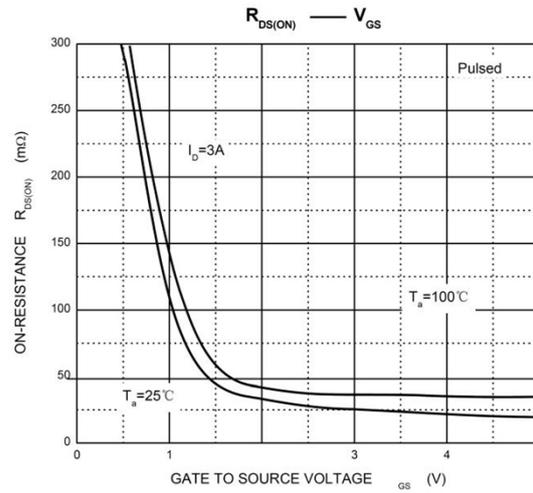
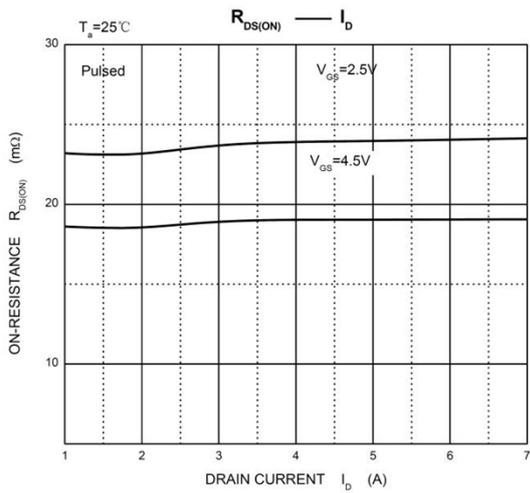
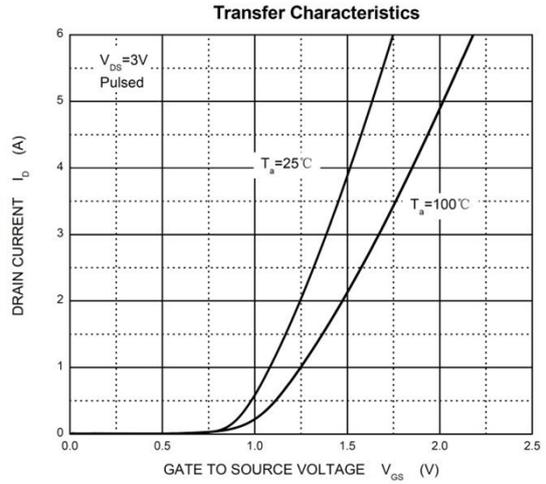
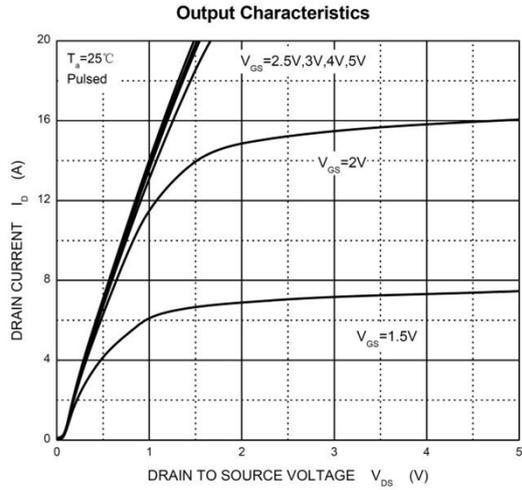
Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	20	V
Gate-Source Voltage	V_{GS}	± 12	V
Continuous Drain Current($t \leq 10\text{s}$)	I_D	5	A
Pulsed Drain Current	I_{DM}	25	A
Power Dissipation($t \leq 10\text{s}$)	P_D	1.5	W
Thermal Resistance from Junction to Ambient($t \leq 10\text{s}$)	$R_{\theta JA}$	83.3	$^{\circ}\text{C}/\text{W}$
Junction Temperature	T_J	150	$^{\circ}\text{C}$
Storage Temperature	T_{STG}	-55~ +150	$^{\circ}\text{C}$

Electrical characteristics

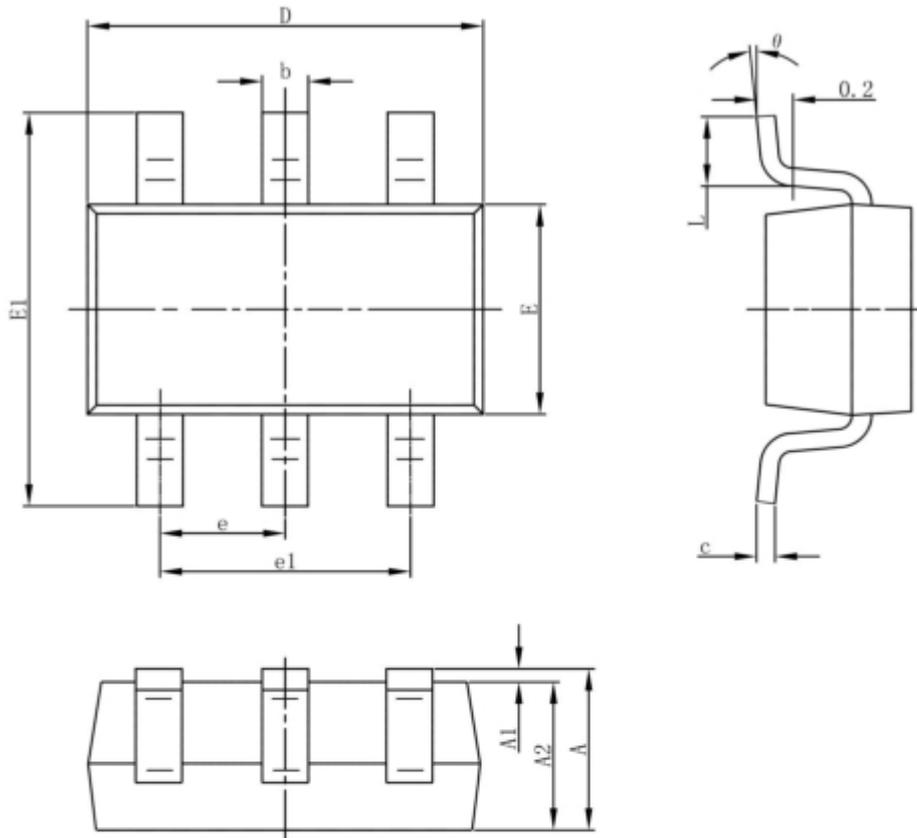
($T_A=25^\circ\text{C}$, unless otherwise noted)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-source breakdown voltage	$BV_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	20			V
Zero gate voltage drain current	I_{DSS}	$V_{DS} = 20V, V_{GS} = 0V$			1	μA
Gate-body leakage current	I_{GSS}	$V_{GS} = \pm 12V, V_{DS} = 0V$			± 0.1	μA
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	0.5	0.66	1.2	V
Drain-source on-resistance	$R_{DS(on)}$	$V_{GS} = 4.5V, I_D = 4.5A$	12	18	27	m Ω
		$V_{GS} = 4.2V, I_D = 4.5A$	12.5	19.5	28.5	
		$V_{GS} = 3.8V, I_D = 4A$	13	21	30	
		$V_{GS} = 3.1V, I_D = 3.5A$	14	22.5	31	
		$V_{GS} = 2.5V, I_D = 3.5A$	15	24	32	
Forward transconductance	g_{FS}	$V_{DS} = 5V, I_D = 7A$	9			S
Diode forward voltage	V_{SD}	$I_S = 1.7A, V_{GS} = 0V$		0.77	1.2	V
Dynamic Characteristics						
Total Gate Charge	Q_g	$V_{DS} = 10V, V_{GS} = 4.5V, I_D = 4A$		11		nC
Gate-Source Charge	Q_{gs}			2.3		
Gate-Drain Charge	Q_{gd}			2.5		
Input capacitance	C_{iss}	$V_{DS} = 8V, V_{GS} = 0V, f = 1MHz$		800		pF
Output capacitance	C_{oss}			155		
Reverse transfer capacitance	C_{rss}			125		
Switching Characteristics						
Turn-on Delay Time	$T_{d(on)}$	$V_{DD} = 10V, V_{GS} = 4V, I_D = 1A, R_{GEN} = 10\Omega$		18		nS
Turn-on Rise Time	T_r			5		
Turn-Off Delay Time	$T_{d(off)}$			43		
Turn-Off Fall Time	t_f			20		

Typical Characteristics

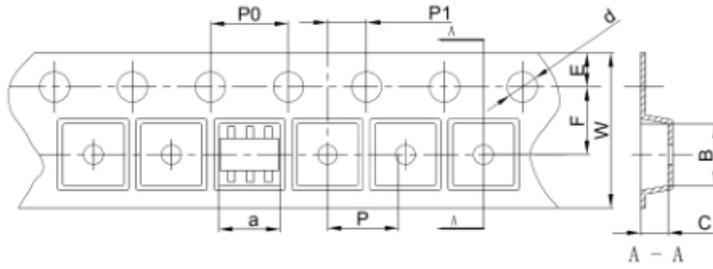


SOT-23-6L Package Information



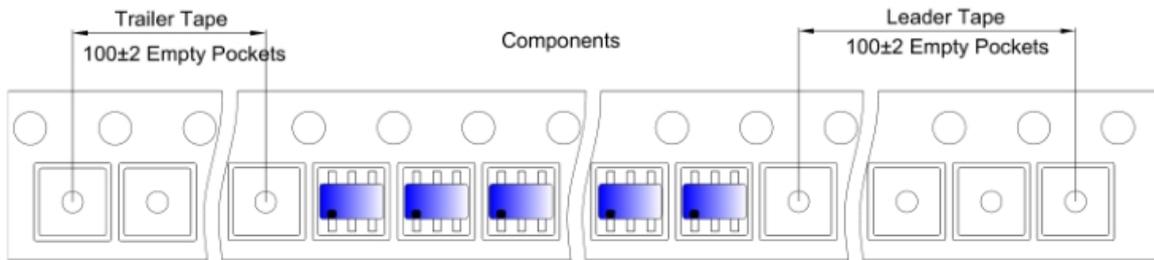
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
theta	0°	8°	0°	8°

SOT-23-6L Embossed Carrier Tape

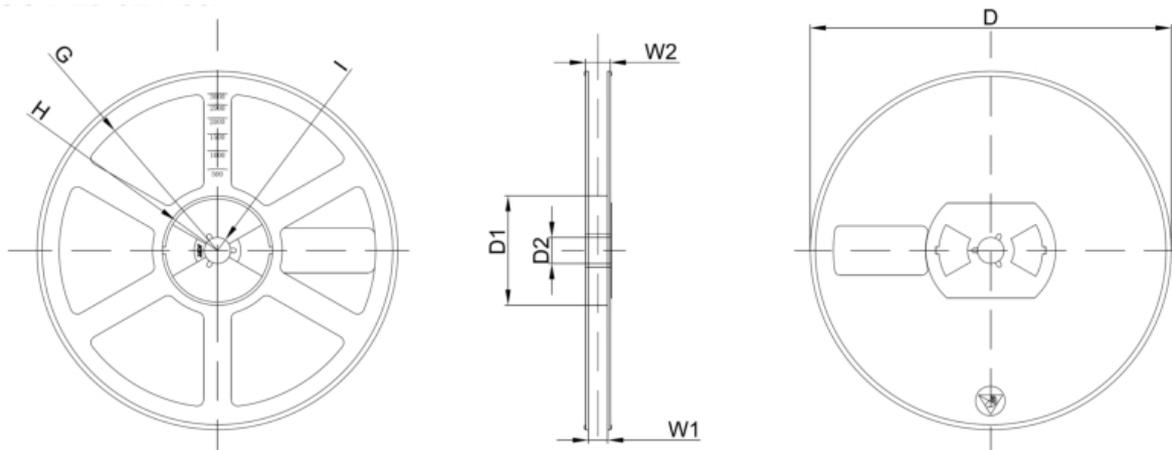


Dimensions are in millimeter										
Pkg type	a	B	C	d	E	F	P0	P	P1	W
SOT-23-6L	3.17	3.23	1.37	Ø1.55	1.75	3.50	4.00	4.00	2.00	8.00

SOT-23-6L Tape Leader and Trailer



SOT-23-6L Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
7" Dia	Ø180.00	60.00	13.00	R78.00	R25.60	R6.50	9.50	13.10

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	30,000 pcs	203×203×195	120,000 pcs	438×438×220	